TLV760 100mA 30V 固定输出线性电压调整器

1 特性

- 高达 30V 的宽输入电压范围
- 高达 100mA 的输出电流
- 提供固定输出电压 3.3V、5V、12V 和 15V 版本
- 运行结温范围为 −40°C 至 +125°C
- 接 0.1µF及以上 的陶瓷电容器保持稳定工作
- 有效的热保护和电流限制

2 应用

- 用于开关直流/直流转换器的后置稳压器
- 用于数字和模拟电路的偏置电源
- 家用电器
- 电动工具
- 工厂和楼宇自动化

3 说明

TLV760 是一款集成的线性电压调整器，能够以高达 30V 的输入电压运行。在运行温度范围内，TLV760 可在 100mA 满负载下具有 1.2V 的最大压降。TLV760 的标准封装是 3 引脚 SOT-23 封装。

TLV760 提供 3.3V、5V、12V 和 15V 版本。TLV760 系列的 SOT-23 封装允许器件用于空间受限的 应用。TLV760 是 LM78Lxx 系列和类似器件的小尺寸替代产品。

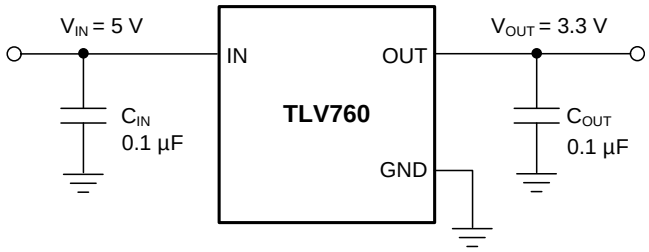
TLV760 用于对遭受高达 30V 的电源瞬态和尖峰的 应用 （例如电器和自动化应用）中的数字和模拟电路进行 偏置。该器件具有可靠的内部热保护功能，可以保护其自身免受由接地短路、环境温度升高、高负载或高压降事件等情况导致的潜在损害。

器件信息(1)

器件型号	封装	封装尺寸（标称值）
TLV760	SOT-23 (3)	2.92mm × 1.30mm

(1) 如需了解所有可用封装，请参阅产品说明书末尾的可订购产品附录。

典型应用电路



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4 修订历史记录

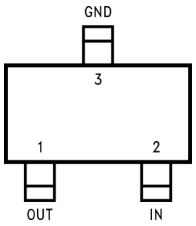
注：之前版本的页码可能与当前版本有所不同。

Changes from Original (June 2017) to Revision A	**Page**
• Changed description of pin 1 to "OUT" and pin 2 to "IN" to correct error	3

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5 Pin Configuration and Functions

DBZ Package
3-Pin SOT-23
Top View



Pin Functions

PIN		I/O	DESCRIPTION
NO.	NAME		
1	OUT	O	Output voltage, a ceramic capacitor greater than or equal to 0.1 μF is need for the stability of the device. (1)
2	IN	I	Input voltage supply — TI recommends a capacitor of value greater than 0.1 μF at the input. (1)
3	GND	—	Common ground

(1) See *External Capacitors* for more details.

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6 Specifications

6.1 Absolute Maximum Ratings(1)

	MIN	MAX	UNIT
Input voltage (IN to GND)	–0.3	35	V
Output Voltage (OUT)		V_{IN} + 0.3	V
Output Current		Internally limited(2)	mA
Junction temperature	–40	150	°C
Storage temperature, T_{stg}	−65	150	°C

(1) Stresses beyond those listed under *Absolute Maximum Ratings*(1) may cause permanent damage to the device. These are stress ratings only, which do not imply functional operation of the device at these or any other conditions beyond those indicated under *Recommended Operating Conditions*. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.
(2) See *Recommended Operating Conditions* section for more details.

6.2 ESD Ratings

			VALUE	UNIT
$V_{(ESD)}$	Electrostatic discharge	Human-body model (HBM), per ANSI/ESDA/JEDEC JS-001(1)	±2000	V
		Charged-device model (CDM), per JEDEC specification JESD22-C101(2)	±500	

(1) JEDEC document JEP155 states that 500-V HBM allows safe manufacturing with a standard ESD control process.
(2) JEDEC document JEP157 states that 250-V CDM allows safe manufacturing with a standard ESD control process.

6.3 Recommended Operating Conditions

over operating free-air temperature range (unless otherwise noted)

	MIN	MAX	UNIT
Maximum input voltage (IN to GND)		30	V
Output current (I_{OUT})		100	mA
Input and output capacitor (C_{OUT})	0.1		µF
Junction temperature, T_J	–40	125	°C

6.4 Thermal Information

THERMAL METRIC(1)		TLV760 DBZ (SOT-23) 3 PINS	UNIT
$R_{\theta JA}$	Junction-to-ambient thermal resistance	275.2	°C/W
$R_{\theta JC(top)}$	Junction-to-case (top) thermal resistance	92.8	°C/W
$R_{\theta JB}$	Junction-to-board thermal resistance	56.8	°C/W
ψ_{JT}	Junction-to-top characterization parameter	2.9	°C/W
ψ_{JB}	Junction-to-board characterization parameter	55.6	°C/W

(1) For more information about traditional and new thermal metrics, see the *Semiconductor and IC Package Thermal Metrics* application report.

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6.5 Electrical Characteristics

Typical and other limits apply for $T_A = T_J = 25°C$, $V_{OUT(NOM)}$ = 3.3 V, 5 V, 12 V, and 15 V, unless otherwise specified.

PARAMETER		TEST CONDITIONS		MIN	TYP	MAX	UNIT
V_{OUT}	Output voltage accuracy	$V_{IN} = V_{OUT(NOM)}$+ 1.5 V, 1 mA ≤ I_{OUT} ≤ 100 mA		–4%		4%	V
		$V_{IN} = V_{OUT(NOM)}$ + 1.5 V, 1 mA ≤ I_{OUT} ≤ 100 mA, −40°C ≤ T_J ≤ 125°C		–5%		5%	
$\Delta V_{(\Delta VIN)}$	Line regulation	$V_{OUT(NOM)}$ + 1.5 V ≤ V_{IN} ≤ 30 V, I_{OUT} = 1 mA , −40°C ≤ T_J ≤ 125°C	$V_{OUT(NOM)}$ = 3.3 V, 5 V		10	30	mV
			$V_{OUT(NOM)}$ = 12 V, 15 V		14	45	
$\Delta V_{(\Delta IOUT)}$	Load regulation	V_{IN} =$V_{OUT(NOM)}$ + 1.5 V , 10 mA ≤ I_{OUT} ≤ 100 mA, −40°C ≤ T_J ≤ 125°C	$V_{OUT(NOM)}$ = 3.3 V, 5 V		20	45	mV
			$V_{OUT(NOM)}$ = 12 V, 15 V		45	80	
I_{GND}	Ground pin current	$V_{OUT(NOM)}$ + 1.5 V ≤ V_{IN} ≤ 30 V, no load, −40°C ≤ T_J ≤ 125°C			2	5	mA
V_{DO}	Dropout voltage	I_{OUT} = 10 mA			0.7	0.9	V
		I_{OUT} = 10 mA , −40°C ≤ T_J ≤ 125°C				1	
		I_{OUT} = 100 mA			0.9	1.1	
		I_{OUT} = 100 mA, −40°C ≤ T_J ≤ 125°C				1.2	
T_{SD}	Thermal shutdown temperature				150		°C

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6.6 Typical Characteristics

Unless indicated otherwise, $V_{IN} = V_{NOM} + 1.5$ V, $C_{IN} = 0.1$ µF, $C_{OUT} = 0.1$ µF, and $T_A = 25°C$.

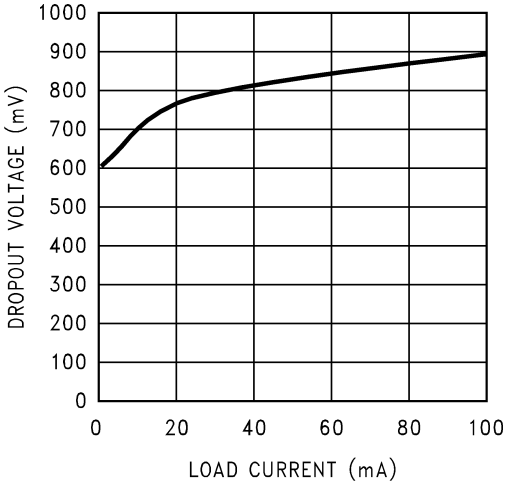


Figure 1. Dropout Voltage vs Load Current

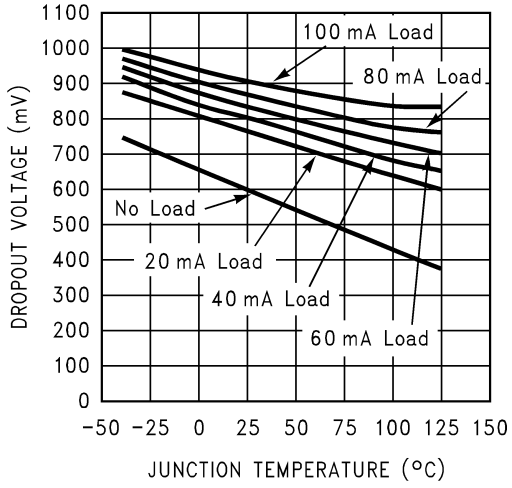


Figure 2. Dropout Voltage vs Junction Temperature

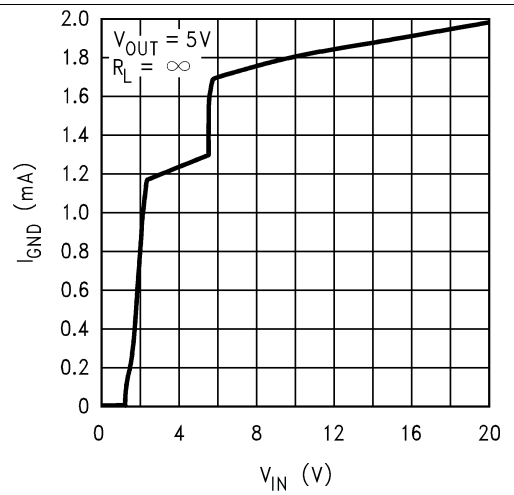


Figure 3. Ground Pin Current vs Input Voltage

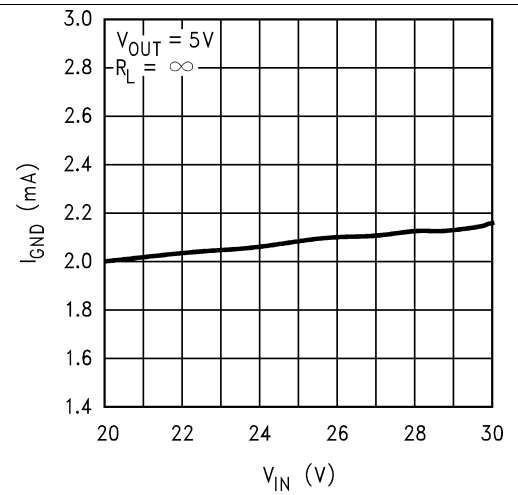


Figure 4. Ground Pin Current vs Input Voltage

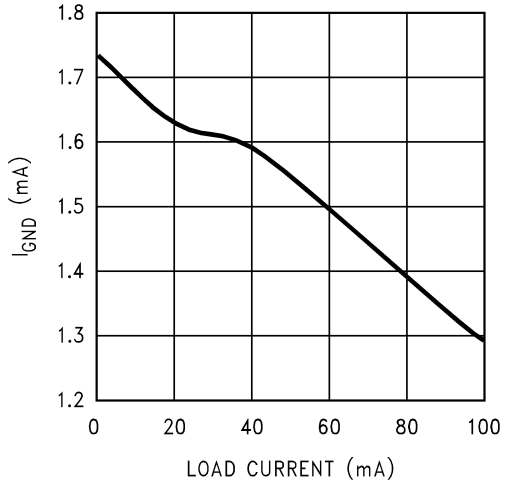


Figure 5. Ground Pin Current vs Load Current

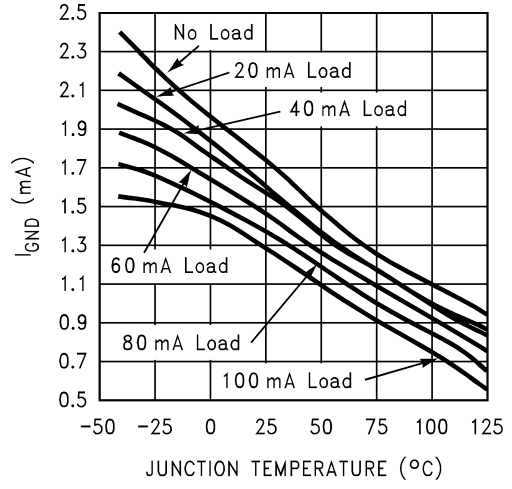


Figure 6. Ground Pin Current vs Junction Temperature

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Typical Characteristics (continued)

Unless indicated otherwise, $V_{IN} = V_{NOM} + 1.5$ V, $C_{IN} = 0.1$ µF, $C_{OUT} = 0.1$ µF, and $T_A = 25°C$.

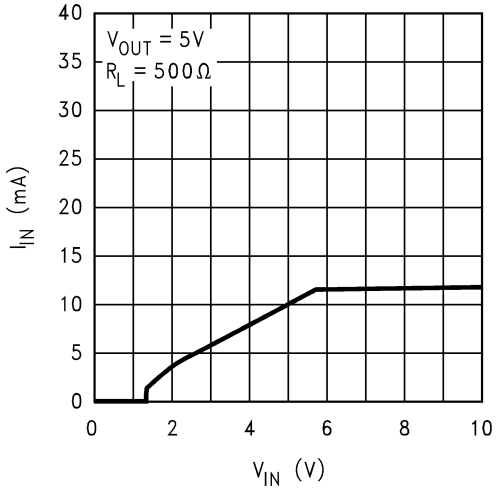


Figure 7. Input Current vs Input Voltage

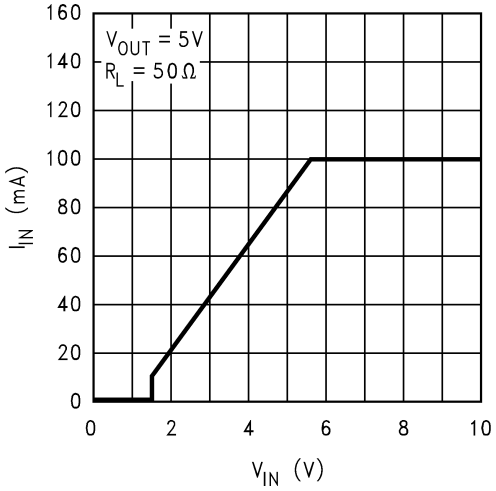


Figure 8. Input Current vs Input Voltage

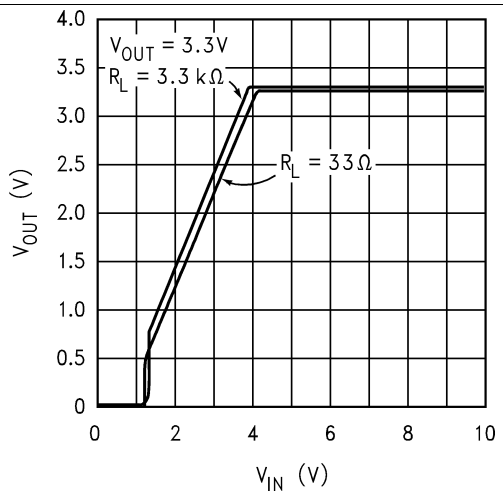


Figure 9. Output Voltage vs Input Voltage

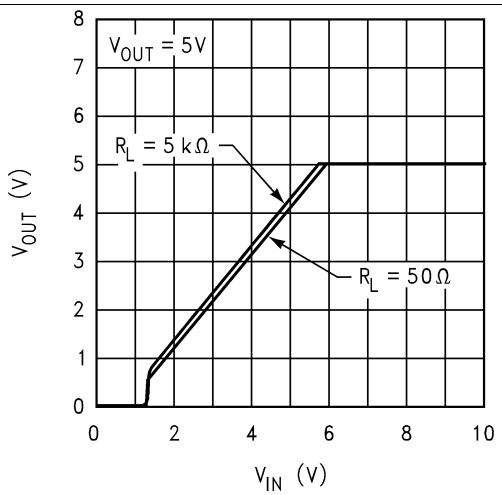


Figure 10. Output Voltage vs Input Voltage

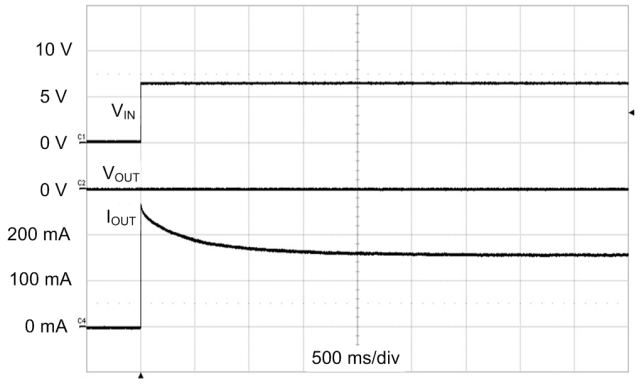


Figure 11. Output Short-Circuit Current

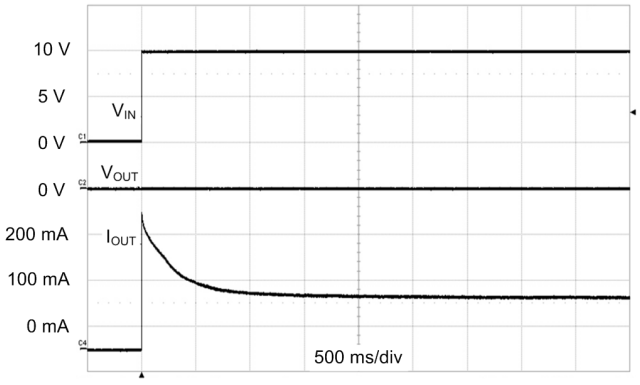


Figure 12. Output Short-Circuit Current

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Typical Characteristics (continued)

Unless indicated otherwise, $V_{IN} = V_{NOM} + 1.5$ V, $C_{IN} = 0.1$ µF, $C_{OUT} = 0.1$ µF, and $T_A = 25°C$.

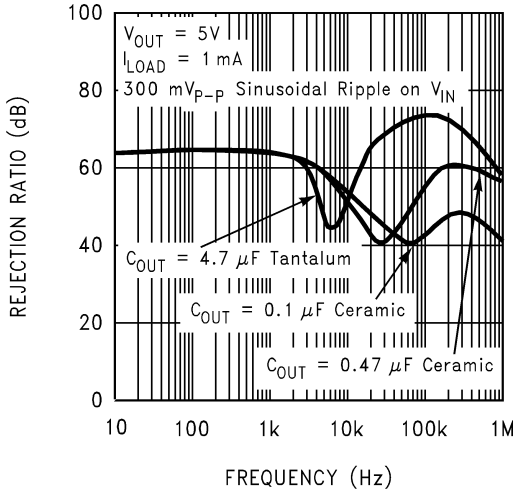


Figure 13. Power Supply Rejection Ratio

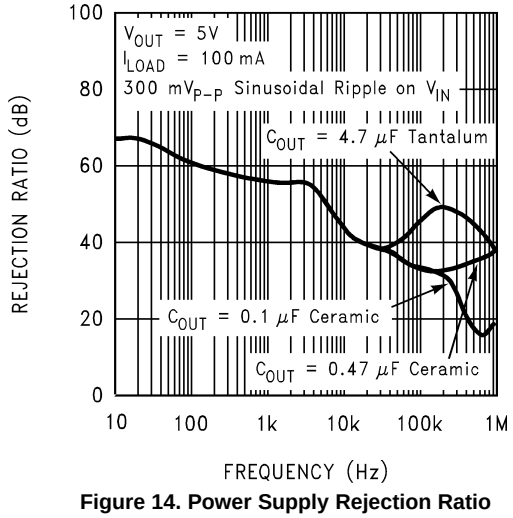


Figure 14. Power Supply Rejection Ratio

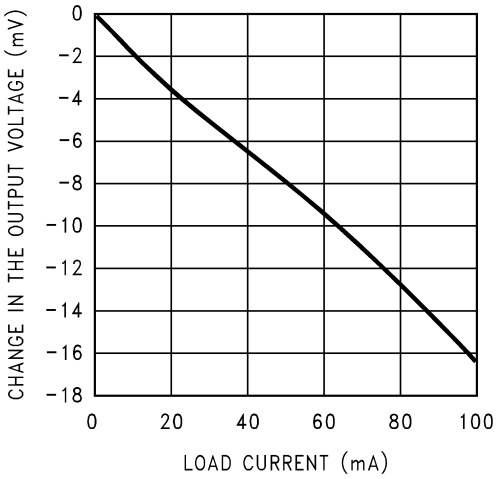
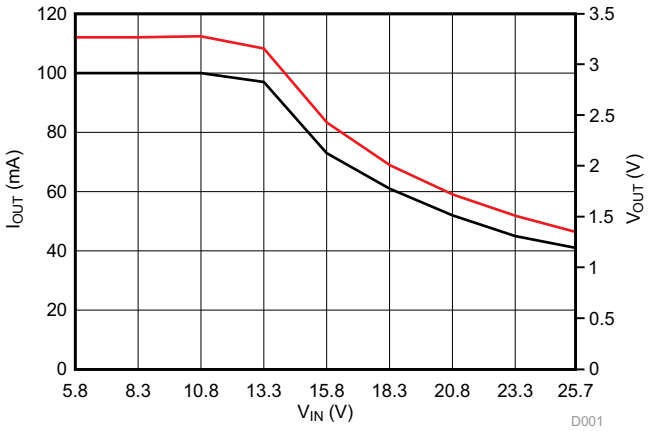


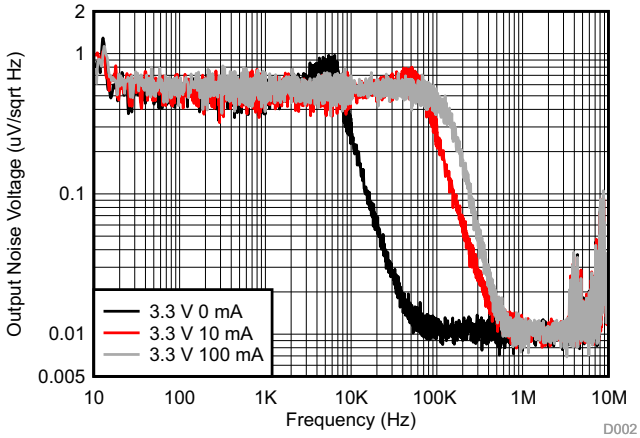
Figure 15. DC Load Regulation



V_{OUT}(Red) = 3.3 V

I_{OUT}(Black) = 100 mA

Figure 16. Output Current vs Input Voltage



C_{IN} = 1 µF C_{OUT} = 0.1 µF V_{OUT} = 3.3 V

Figure 17. Output Spectral Noise Density vs Frequency

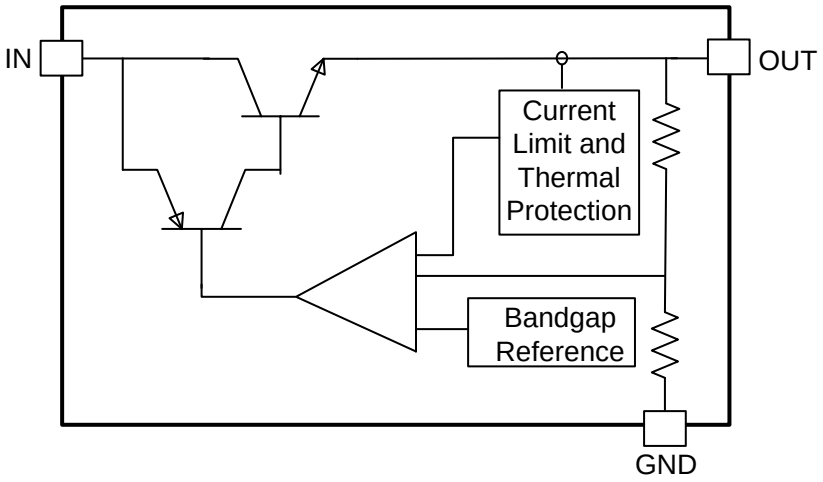
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7 Detailed Description

7.1 Overview

The TLV760 is an integrated linear-voltage regulator with inputs that can be as high as 30 V. The TLV760 features quasi LDO architecture, which allows the usage of low ESR capacitors at the output. A ceramic capacitor with a capacitance value greater than or equal to 0.1 µF is adequate to keep the linear regulator in stable operation. The device has a rugged active junction thermal protection mechanism.

7.2 Functional Block Diagram



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7.3 Feature Description

7.3.1 Thermal Protection

The TLV760 contains an active thermal protection mechanism, which limits the junction temperature to 150°C. This protection comes into action when the thermal junction temperature of the device tries to exceed 150°C. The output current of the device is limited or folded back to maintain the junction temperature.

The thermal protection follows Equation 1

$$P_D = (T_J - T_A) / R_{\theta JA} \quad (1)$$

where

- $P_D = (V_{IN} - V_{OUT})I_{OUT}$
- T_J is the junction temperature
- $R_{\theta JA}$ is the junction-to-ambient thermal resistance

When a high drop out condition occurs resulting in higher power dissipation across the device the output current is limited to maintain a constant junction temperature of 150°C. This rugged feature protects the device from higher power dissipation applications as well as the short to ground at the output.

This internal protection circuitry of TLV760 is intended to protect the devices against thermal overload conditions. The circuitry is not intended to replace proper heat sinking. Continuously running the TLV760 into thermal protection degrades device reliability.

For reliable operation, limit junction temperature to a maximum of 125°C. To estimate the thermal margin in a given layout, increase the ambient temperature until the thermal protection is triggered using worst case load and highest input voltage conditions.

Feature Description (continued)

7.3.2 Dropout Voltage

The TLV760 is a bipolar device with quasi LDO architecture. Being a bipolar device the dropout voltage of the device does not change significantly with output load current. The device has a maximum dropout across temperature of 1.2 V at 100-mA load current, which is a significant improvement over the traditional LM78Lxx devices.

7.4 Device Functional Modes

7.4.1 Normal Operation

The TLV760 operates with an input up to 30 V. Its tiny SOT-23 package and quasi-LDO architecture makes it suitable for providing a very tiny 100-mA bias supply. The device regulates to the nominal output voltage when all of the following conditions are met.

- The input voltage is greater than the nominal output voltage plus the dropout voltage ($V_{OUT(NOM)}$ + V_{DO}).
- The output current is less than or equal to 100 mA.
- The device junction temperature is less than the thermal protection temperature of 150°C.

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8 Application and Implementation

NOTE

Information in the following applications sections is not part of the TI component specification, and TI does not warrant its accuracy or completeness. TI's customers are responsible for determining suitability of components for their purposes. Customers should validate and test their design implementation to confirm system functionality.

8.1 Application Information

The TLV760 is a fixed output device which need only input and output capacitors to function. This section discusses the key aspects to implement this linear regulator in typical applications.

8.1.1 Fixed Output

TLV760 comes in fixed output voltage options, 3.3 V, 5 V, 12 V and 15 V. To ensure the proper regulated output, the input voltage should be greater than $V_{OUT(nom)} + V_{DO}$.

8.1.2 External Capacitors

8.1.2.1 Input and Output Capacitor Requirements

A minimum input and output capacitance value of 0.1 µF is required for stability and adequate transient performance. There is no specific equivalent series resistance (ESR) limitation, although excessively high ESR compromises transient performance. There is no specific limitation on a maximum capacitance value on the input or the output. However while selecting a capacitor, derating factors on the capacitance value should be considered. Use C0G, X7R, or X5R-type ceramic capacitors because these capacitors have minimal variation in capacitance value and ESR over temperature.

8.1.2.2 Load-Step Transient Response

The load-step transient response is the output voltage response by the linear regulator to a step change in load current. The depth of charge depletion immediately after the load step is directly proportional to the amount of output capacitance. However, larger output capacitances decrease any voltage dip or peak occurring during a load step, the control-loop bandwidth is also decreased, thereby slowing the response time. TI recommends to optimally scale output capacitors for a specific application and test for the output load transients.

8.1.3 Power Dissipation

Proper consideration should be given to device power dissipation, location of the circuit on the printed circuit board (PCB), and correct sizing of the thermal plane to ensure the device reliability. The PCB area around the regulator must be as free as possible of other heat-generating devices that cause added thermal stresses. To first-order approximation, power dissipation in the regulator depends on the input-to-output voltage difference and load conditions. Power dissipation can be calculated using The thermal protection follows Equation 1:

$$P_D = (T_J - T_A) / R_{\theta JA} \quad (2)$$

where

- $P_D = (V_{IN} - V_{OUT})I_{OUT}$
- T_J is the junction temperature
- $R_{\theta JA}$ is the junction-to-ambient thermal resistance

Thus, at a given load current, input and output voltage, maximum power dissipation determines the maximum allowable ambient temperature (T_A) for the device, and vice versa. Power dissipation and junction temperature are most often related by the junction-to-ambient thermal resistance ($R_{\theta JA}$) of the combined PCB and device package and the temperature of the ambient air (T_A).

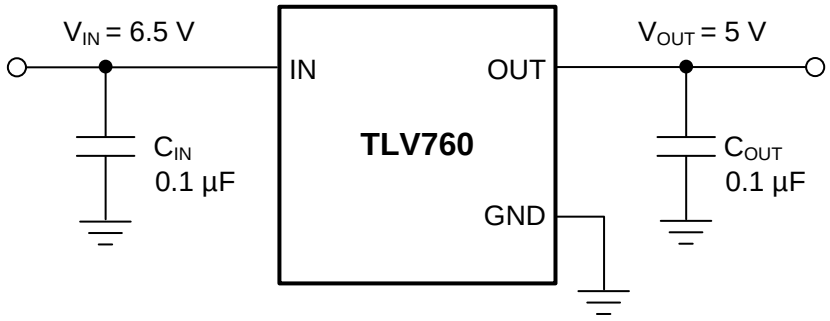
$R_{\theta JA}$ is highly dependent on the heat-spreading capability built into the particular PCB design, and therefore varies according to the total copper area, copper weight, and location of the planes. The $R_{\theta JA}$ recorded in *Thermal Information* is determined by the JEDEC standard, PCB, and copper-spreading area and is only used as a relative measure of package thermal performance.

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Application Information (continued)

TLV760 integrates a rugged protection where the T_J is limited to 150°C. The maximum power dissipation depends on the ambient temperature and can be calculated using $P_D = (T_J – T_A) / R_{\theta JA}$, for example, substituting the absolute maximum junction temperature, 150°C for T_J, 50°C for T_A, and 275.2 °C/W for $R_{\theta JA}$, the maximum power that can be dissipated is 363 mW. More power can be safely dissipated at lower ambient temperatures. Less power can be safely dissipated at higher ambient temperatures. The power dissipation can be increased by 3.6 mW for each °C below 50°C ambient. It must be derated by 3.6 mW for each °C above 50°C ambient. Proper heat sinking enables the safe dissipation of more power.

8.2 Typical Application



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Figure 18. Typical Appication for the 5-V Option

8.2.1 Design Requirements

For typical TLV760 applications, use the parameters in Table 1.

Table 1. Design Parameters

DESIGN PARAMETER	EXAMPLE VALUE
Input voltage	6.5 V
Output voltage	5 V
Output current	100 mA

8.2.2 Detailed Design Procedure

The output for TLV76050 is internally set to 5 V. Input and output capacitors can be selected in accordance with the *External Capacitors*. Ceramic capacitances of 0.1 µF for both input and output are selected.

See the *Layout* section for an example of how to PCB layout the TLV760 to achieve best performance.

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8.2.3 Application Curves

Unless indicated otherwise, V_{IN} = 6.5 V, V_{OUT} = 5 V, C_{OUT} = 0.1 µF, and T_A = 25°C.

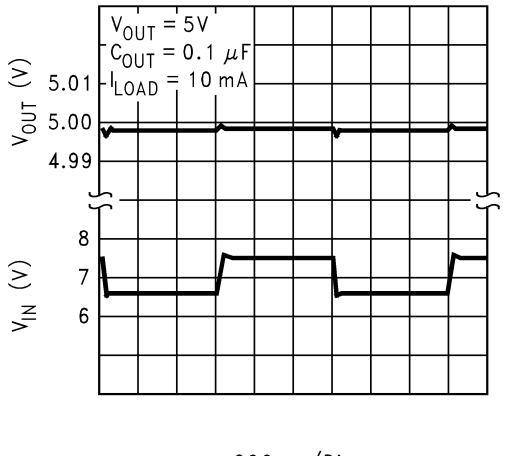


Figure 19. Line Transient Response

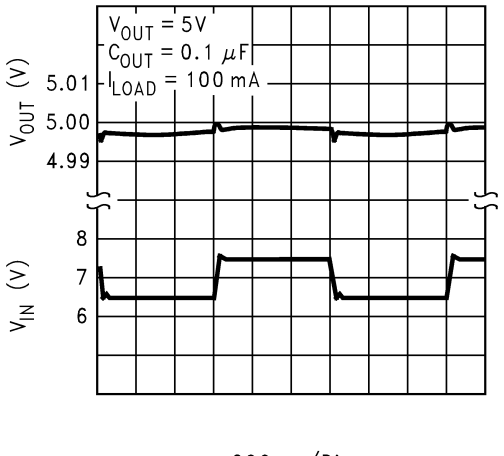


Figure 20. Line Transient Response

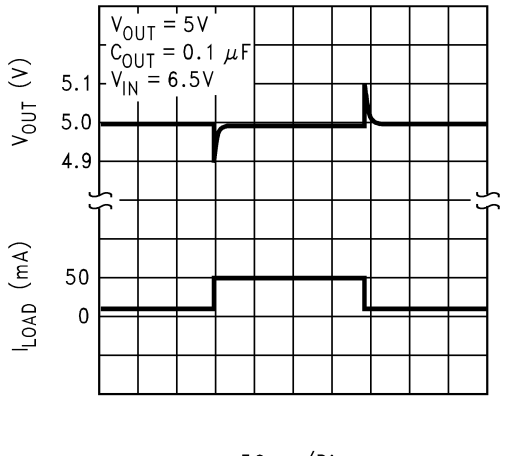


Figure 21. Load Transient Response

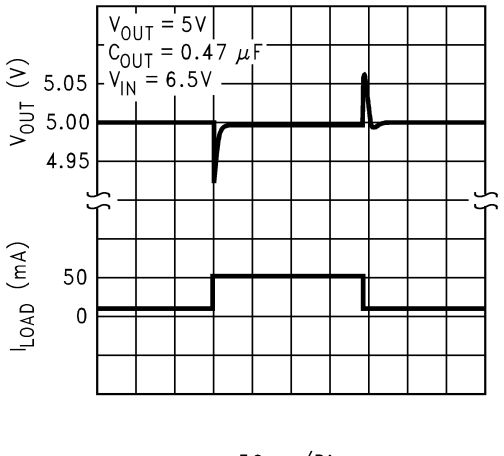


Figure 22. Load Transient Response

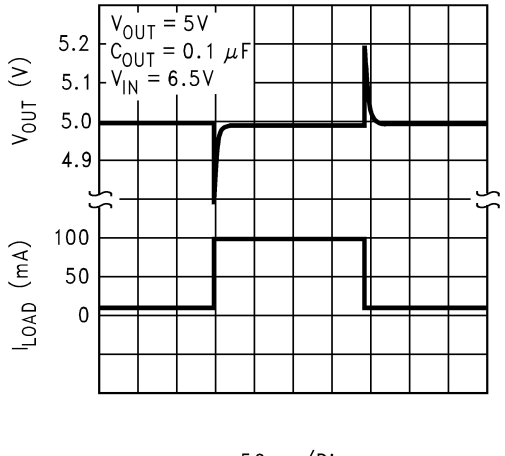


Figure 23. Load Transient Response

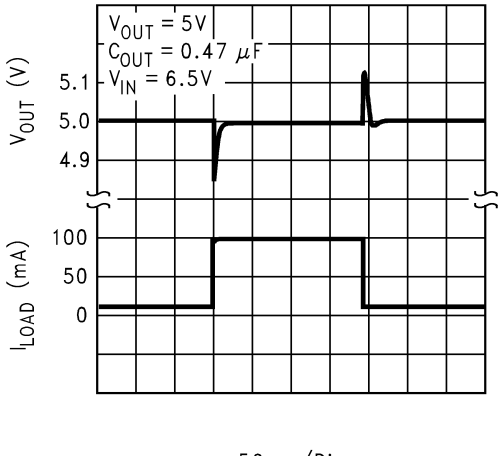


Figure 24. Load Transient Response

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9 Power Supply Recommendations

The TLV760 is designed to operate from input voltage up to 30 V. If the input power supply has ripples, additional input and output capacitors with low ESR can help improve the PSRR at higher frequencies.

10 Layout

10.1 Layout Guidelines

General guidelines for linear regulator designs are to place all circuit components on the same side of the circuit board and as near as practical to the respective TLV760 pin connections. Place ground return connections to the input and output capacitors, and to the TLV760 ground pin as close as possible to each other, connected by a wide, component-side, copper surface. The use of vias and long traces to create TLV760 circuit connections is strongly discouraged and negatively affects system performance.

Use a ground reference plane, either embedded in the PCB itself or located on the bottom side of the PCB opposite the components. This reference plane serves to assure accuracy of the output voltage and to shield noise; it behaves similarly to a thermal plane to spread heat from the linear regulator. In most applications, this ground plane is necessary to meet thermal requirements.

10.2 Layout Example

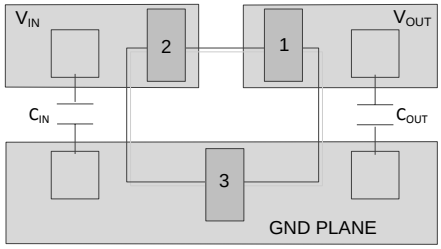


Figure 25. Layout Guideline for TLV760

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11 器件和文档支持

11.1 器件支持

11.1.1 相关文档

请参阅如下相关文档：

《AN-1148 线性稳压器：工作原理和补偿》

11.1.2 Spice 模型

分析模拟电路和系统的性能时，使用 SPICE 模型对电路性能进行计算机仿真非常有用。您可以通过 TLV760 产品文件夹在仿真模型下获取 TLV760 的 SPICE 模型。

11.1.3 器件命名规则

表 **2.** 订购信息 **(1)**

产品	说明
TLV760**XXYYYZ**	**XX** 是电压符号 **YYY** 是封装符号。 **Z** 为封装数量。

(1) 欲获得最新的封装和订货信息，请参阅本文档末尾的封装选项附录，或者访问 www.ti.com 查看器件产品文件夹。

11.2 接收文档更新通知

要接收文档更新通知，请转至 TI.com 上的器件产品文件夹。单击右上角的*通知我* 进行注册，即可每周接收产品信息更改摘要。有关更改的详细信息，请查看任何已修订文档中包含的修订历史记录。

11.3 社区资源

下列链接提供到 TI 社区资源的连接。链接的内容由各个分销商“按照原样”提供。这些内容并不构成 TI 技术规范，并且不一定反映 TI 的观点；请参阅 TI 的 《使用条款》。

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11.4 商标

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All other trademarks are the property of their respective owners.

11.5 静电放电警告



这些装置包含有限的内置 ESD 保护。 存储或装卸时，应将导线一起截短或将装置放置于导电泡棉中，以防止 MOS 门极遭受静电损伤。

11.6 Glossary

SLYZ022 — *TI Glossary*.

This glossary lists and explains terms, acronyms, and definitions.

12 机械、封装和可订购信息

以下页面包含机械、封装和可订购信息。这些信息是指定器件的最新可用数据。这些数据如有变更，恕不另行通知和修订此文档。如欲获取此产品说明书的浏览器版本，请参阅左侧的导航。

PACKAGING INFORMATION

Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan (2)	Lead finish/ Ball material (6)	MSL Peak Temp (3)	Op Temp (°C)	Device Marking (4/5)	Samples
TLV76012DBZR	ACTIVE	SOT-23	DBZ	3	3000	RoHS & Green	SN	Level-1-260C-UNLIM	-40 to 125	18G	Samples
TLV76012DBZT	ACTIVE	SOT-23	DBZ	3	250	RoHS & Green	SN	Level-1-260C-UNLIM	-40 to 125	18G	Samples
TLV76015DBZR	ACTIVE	SOT-23	DBZ	3	3000	RoHS & Green	SN	Level-1-260C-UNLIM	-40 to 125	18C	Samples
TLV76015DBZT	ACTIVE	SOT-23	DBZ	3	250	RoHS & Green	SN	Level-1-260C-UNLIM	-40 to 125	18C	Samples
TLV76033DBZR	ACTIVE	SOT-23	DBZ	3	3000	RoHS & Green	SN	Level-1-260C-UNLIM	-40 to 125	18H	Samples
TLV76033DBZT	ACTIVE	SOT-23	DBZ	3	250	RoHS & Green	SN	Level-1-260C-UNLIM	-40 to 125	18H	Samples
TLV76050DBZR	ACTIVE	SOT-23	DBZ	3	3000	RoHS & Green	SN	Level-1-260C-UNLIM	-40 to 125	18I	Samples
TLV76050DBZT	ACTIVE	SOT-23	DBZ	3	250	RoHS & Green	SN	Level-1-260C-UNLIM	-40 to 125	18I	Samples

(1) The marketing status values are defined as follows:
ACTIVE: Product device recommended for new designs.
LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.
NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.
PREVIEW: Device has been announced but is not in production. Samples may or may not be available.
OBSOLETE: TI has discontinued the production of the device.

(2) **RoHS:** TI defines "RoHS" to mean semiconductor products that are compliant with the current EU RoHS requirements for all 10 RoHS substances, including the requirement that RoHS substance do not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, "RoHS" products are suitable for use in specified lead-free processes. TI may reference these types of products as "Pb-Free".
RoHS Exempt: TI defines "RoHS Exempt" to mean products that contain lead but are compliant with EU RoHS pursuant to a specific EU RoHS exemption.
Green: TI defines "Green" to mean the content of Chlorine (Cl) and Bromine (Br) based flame retardants meet JS709B low halogen requirements of <=1000ppm threshold. Antimony trioxide based flame retardants must also meet the <=1000ppm threshold requirement.

(3) MSL, Peak Temp. - The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

(4) There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.

(5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.

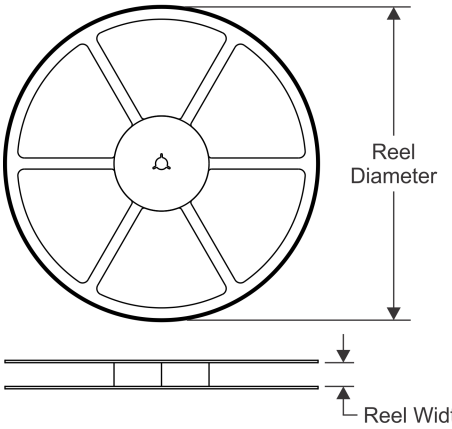
(6) Lead finish/Ball material - Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

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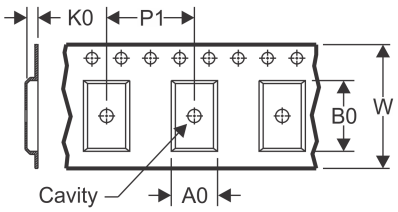
In no event shall TI's liability arising out of such information exceed the total purchase price of the TI part(s) at issue in this document sold by TI to Customer on an annual basis.

TAPE AND REEL INFORMATION

REEL DIMENSIONS

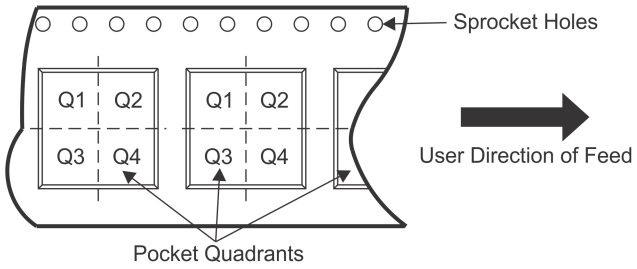


TAPE DIMENSIONS



A0	Dimension designed to accommodate the component width
B0	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

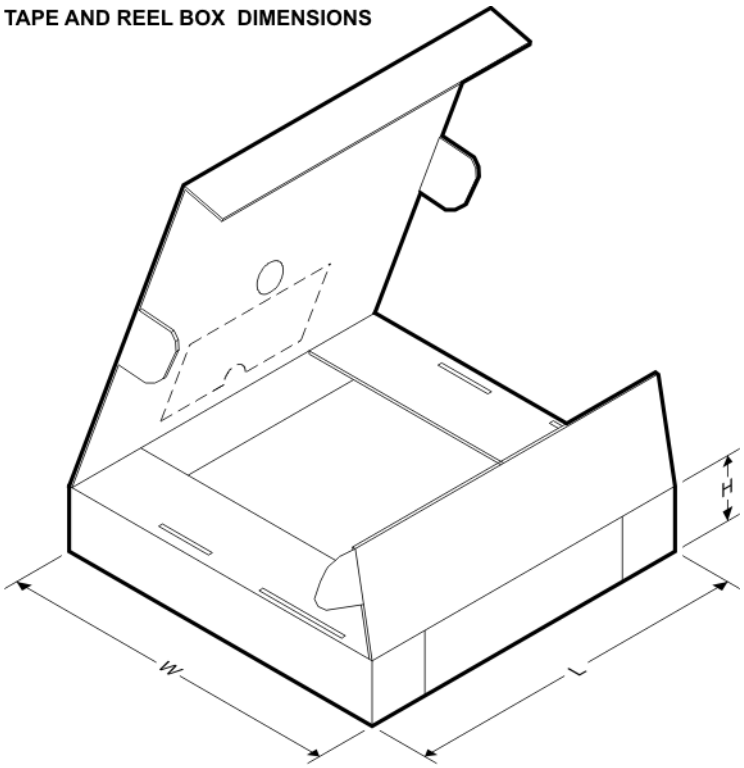
QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
TLV76012DBZR	SOT-23	DBZ	3	3000	178.0	8.4	3.3	2.9	1.22	4.0	8.0	Q3
TLV76012DBZT	SOT-23	DBZ	3	250	178.0	8.4	3.3	2.9	1.22	4.0	8.0	Q3
TLV76015DBZR	SOT-23	DBZ	3	3000	178.0	8.4	3.3	2.9	1.22	4.0	8.0	Q3
TLV76015DBZT	SOT-23	DBZ	3	250	178.0	8.4	3.3	2.9	1.22	4.0	8.0	Q3
TLV76033DBZR	SOT-23	DBZ	3	3000	178.0	8.4	3.3	2.9	1.22	4.0	8.0	Q3
TLV76033DBZT	SOT-23	DBZ	3	250	178.0	8.4	3.3	2.9	1.22	4.0	8.0	Q3
TLV76050DBZR	SOT-23	DBZ	3	3000	178.0	8.4	3.3	2.9	1.22	4.0	8.0	Q3
TLV76050DBZT	SOT-23	DBZ	3	250	178.0	8.4	3.3	2.9	1.22	4.0	8.0	Q3

TAPE AND REEL BOX DIMENSIONS



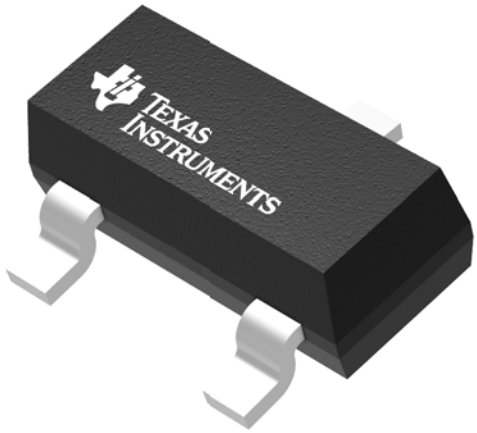
*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
TLV76012DBZR	SOT-23	DBZ	3	3000	208.0	191.0	35.0
TLV76012DBZT	SOT-23	DBZ	3	250	208.0	191.0	35.0
TLV76015DBZR	SOT-23	DBZ	3	3000	208.0	191.0	35.0
TLV76015DBZT	SOT-23	DBZ	3	250	208.0	191.0	35.0
TLV76033DBZR	SOT-23	DBZ	3	3000	208.0	191.0	35.0
TLV76033DBZT	SOT-23	DBZ	3	250	208.0	191.0	35.0
TLV76050DBZR	SOT-23	DBZ	3	3000	208.0	191.0	35.0
TLV76050DBZT	SOT-23	DBZ	3	250	208.0	191.0	35.0

GENERIC PACKAGE VIEW

DBZ 3 SOT-23 - 1.12 mm max height

SMALL OUTLINE TRANSISTOR



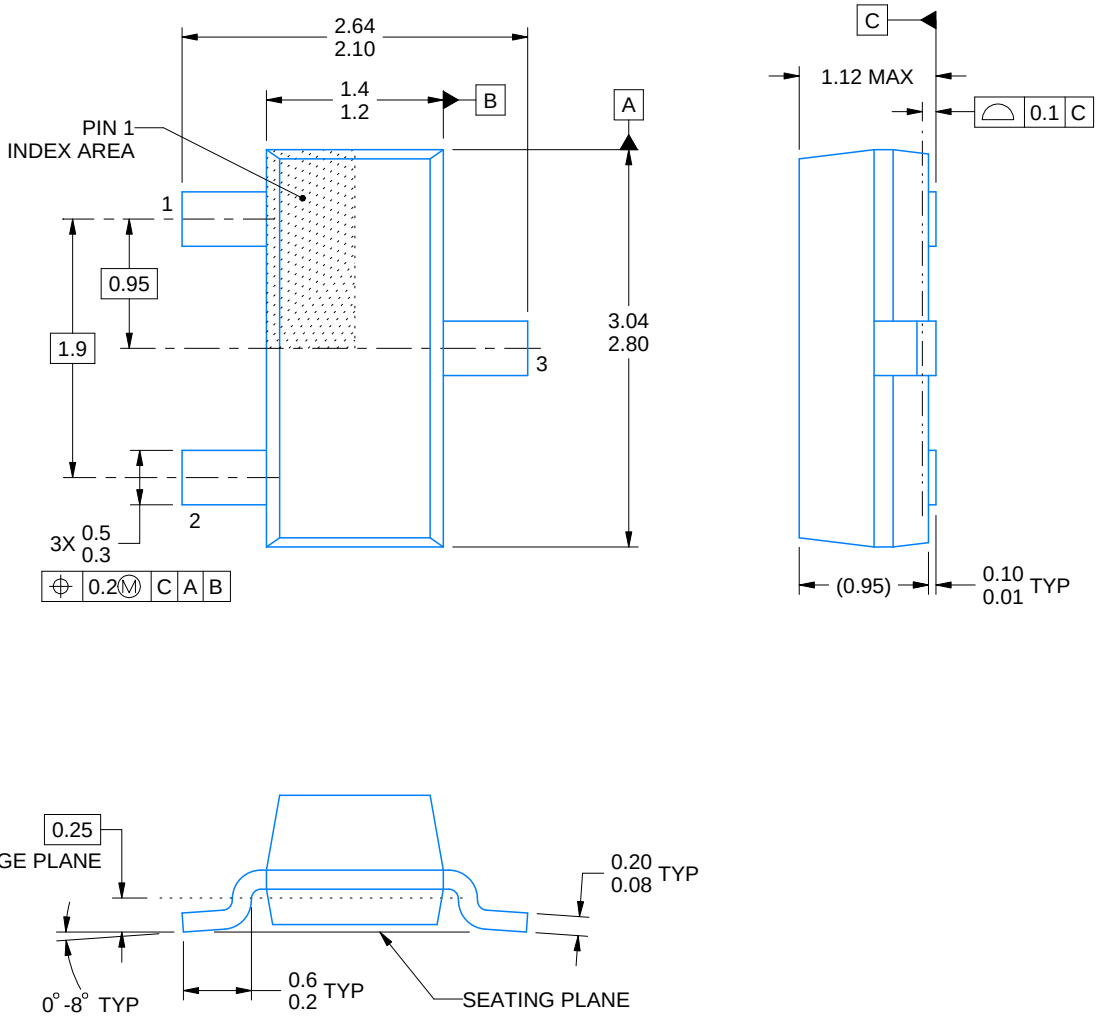
Images above are just a representation of the package family, actual package may vary.
Refer to the product data sheet for package details.

PACKAGE OUTLINE

DBZ0003A

SOT-23 - 1.12 mm max height

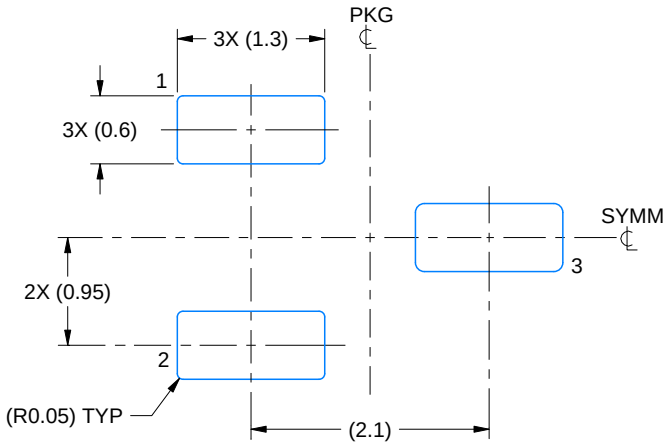
SMALL OUTLINE TRANSISTOR



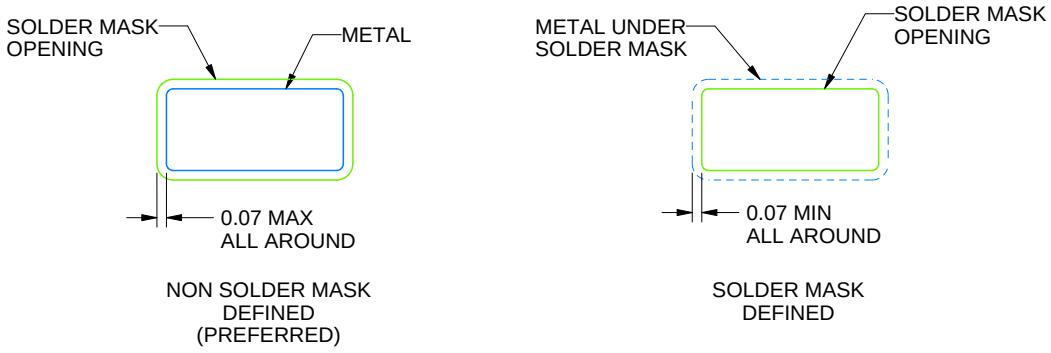
4214838/C 04/2017

NOTES:

1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.
3. Reference JEDEC registration TO-236, except minimum foot length.



LAND PATTERN EXAMPLE
SCALE:15X

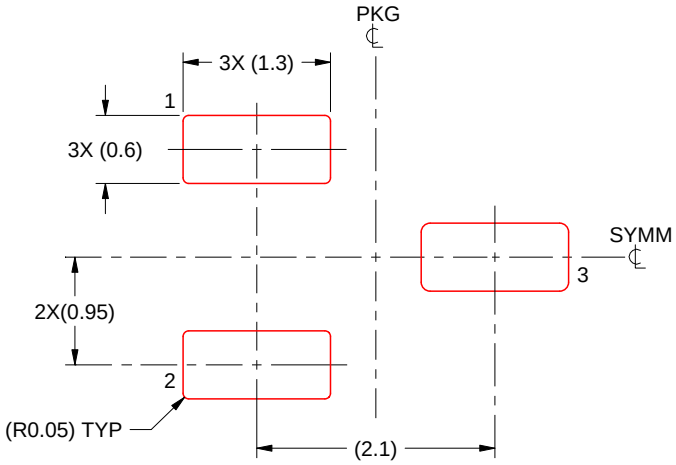


SOLDER MASK DETAILS

4214838/C 04/2017

NOTES: (continued)

4. Publication IPC-7351 may have alternate designs.
5. Solder mask tolerances between and around signal pads can vary based on board fabrication site.



SOLDER PASTE EXAMPLE
BASED ON 0.125 THICK STENCIL
SCALE:15X

4214838/C 04/2017

NOTES: (continued)

6. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
7. Board assembly site may have different recommendations for stencil design.

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